NSN 5961-01-219-6429

No Fiig: A110a0

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-219-6429 **Inclosure Material:** Metal **Overall Length:** 0.185 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: -25.0 gate to source voltage all transistor **Current Rating Per Characteristic:** 50.00 milliamperes gate current all transistor **Power Rating Per Characteristic:** 0.5 watts total power dissipation all transistor **Test Data Document:** 81413-231146 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 8 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**